

1. General description

Planar passivated high commutation three quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/ dt can occur. This "series BT" triac will commutate the full RMS current at the maximum rated junction temperature ($T_{j(max)}$ = 150 °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

2. Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- High junction operating temperature capability
- High voltage capability
- Least sensitive gate for highest noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only

3. Applications

- Applications subject to high temperature
- Heating controls
- High power motor control
- High power switching

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage			-	-	800	V
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$		-	-	200	A
Tj	junction temperature			-	-	150	°C
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 122 °C; <u>Fig. 1</u> ; <u>Fig. 2; Fig. 3</u>		-	-	20	A





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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · ·	I			
I _{GT} gate trigger currer	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 7	-	-	50	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	-	-	50	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	-	50	mA
Dynamic Cl	haracteristics	· · ·		_		
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	1800	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_{D} = 400 \text{ V}; \text{T}_{\text{j}} = 150 \text{ °C}; \text{I}_{\text{T}(\text{RMS})} = 20 \text{ A};$ $dV_{\text{com}}/dt = 10 \text{ V}/\mu\text{s}; \text{ gate open circuit}$	25	-	-	A/ms

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	T2
2	T2	main terminal 2		sym051
3	G	gate		
mb	Τ2	mounting base; main terminal 2	TO-220AB (SOT78)	

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
BTA420-800BT	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78				

7. Marking

Table 4. Marking codes	
Type number	Marking code
BTA420-800BT	BTA420-800BT

8. Limiting values

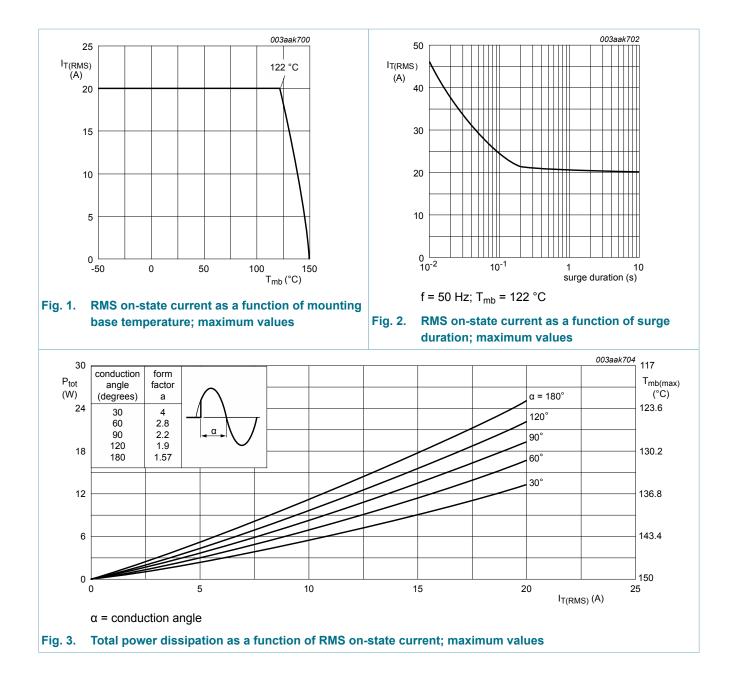
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 122 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	20	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	200	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	220	A
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	200	A ² s
dI _T /dt	rate of rise of on-state current	I_T = 24 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs	-	100	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

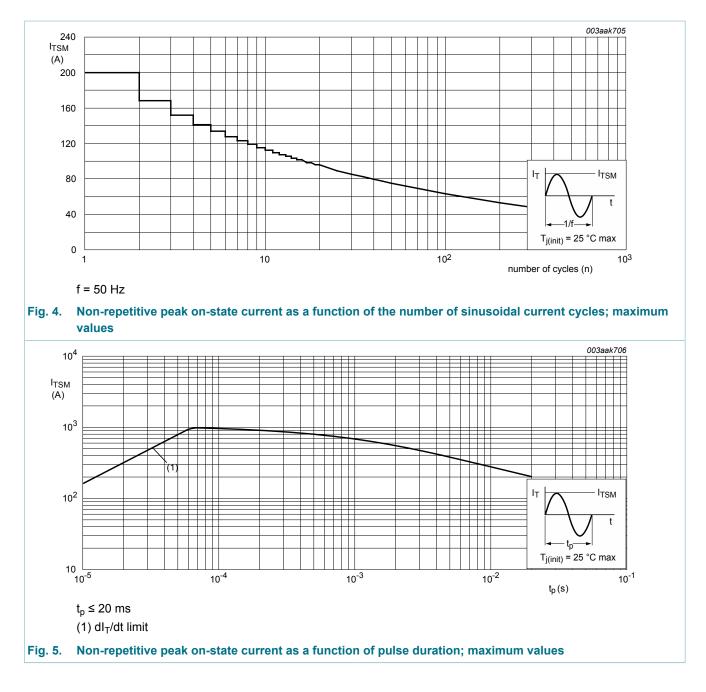
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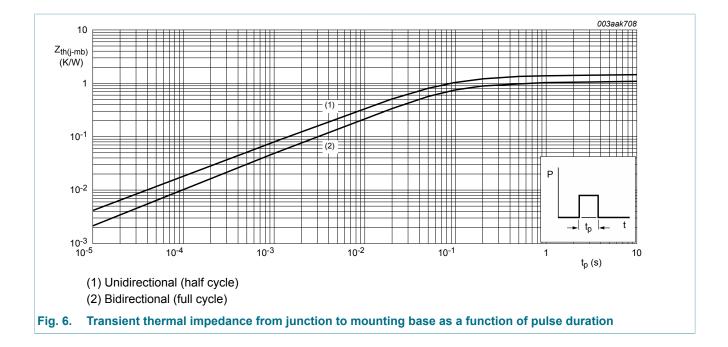


Thermal characteristics 9.

Table 6. T	hermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
frc	thermal resistance	full cycle; Fig. 6		-	-	1.1	K/W
	from junction to mounting base	half cycle; <u>Fig. 6</u>		-	-	1.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		-	60	-	K/W
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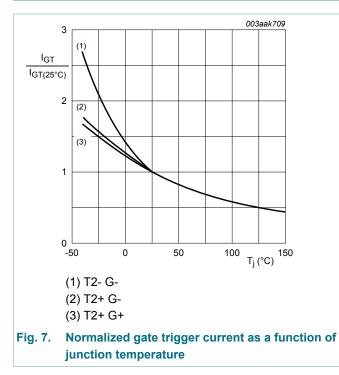
10. Characteristics

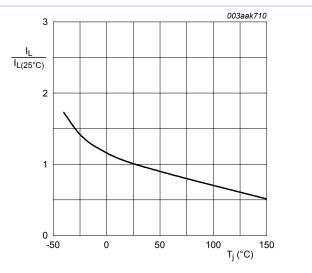
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Static char	acteristics						
I _{GT} gate trigger currer	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; <u>Fig. 7</u>	-	-	50	mA	
	V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>		-	-	50	mA	
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	50	mA	
I _L latching current	L	latching current	V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	60	mA
			V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	90	mA
			V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	60	mA	
V _T	on-state voltage	I _T = 24 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V	
V _{GT}	gate trigger voltage	V _D = 12 V; T _j = 25 °C; <u>Fig. 11</u>	-	0.7	1	V	
		V _D = 400 V; T _j = 150 °C; <u>Fig. 11</u>	0.2	0.4	-	V	
ID	off-state current	V _D = 800 V; T _i = 150 °C		0.2	1	mA	

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Dynamic Characteristics							
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		1800	-	-	V/µs
•••••••••••••••••••••••••••••••••••••••	rate of change of commutating current	$V_{D} = 400 \text{ V}; \text{T}_{\text{j}} = 150 ^{\circ}\text{C}; \text{I}_{\text{T}(\text{RMS})} = 20 \text{ A}; \\ \text{d} \text{V}_{\text{com}}/\text{d} \text{t} = 10 \text{ V}/\mu\text{s}; \text{ gate open circuit}$		25	-	-	A/ms
		V_D = 400 V; T _j = 150 °C; I _{T(RMS)} = 20 A; dV _{com} /dt = 1 V/µs; gate open circuit		65	-	-	A/ms

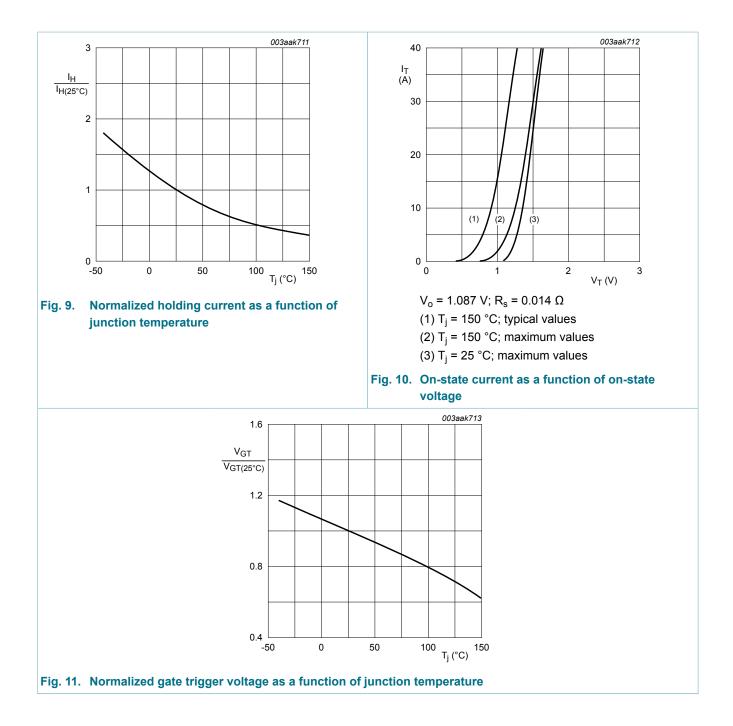






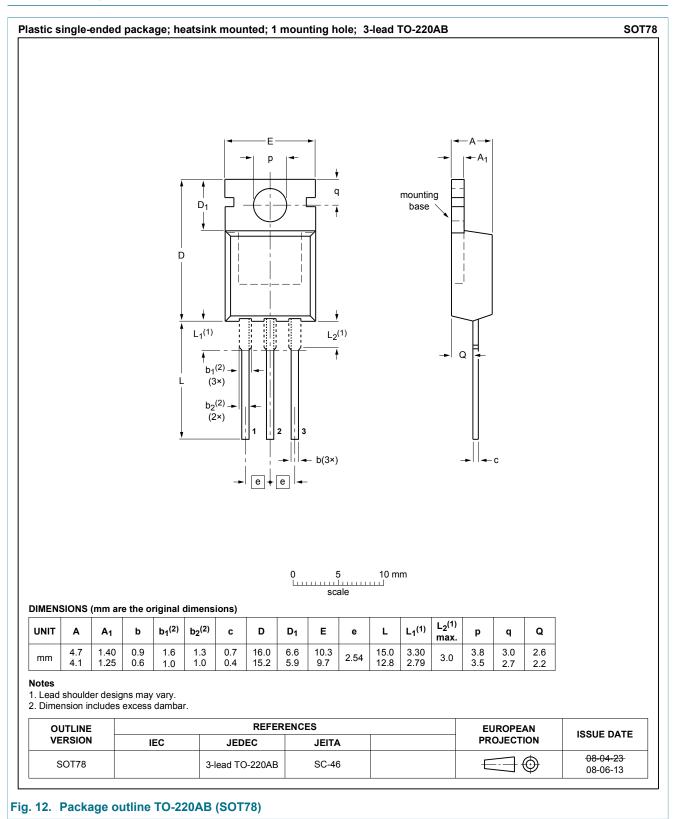
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11. Package outline



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12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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